

isc Silicon NPN Power Transistor

2SC3151

DESCRIPTION

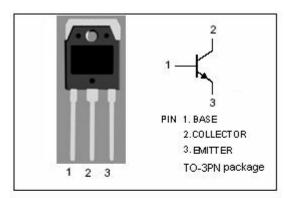
- · High Collector-Emitter Breakdown Voltage-
- : V_{(BR)CEO}= 800V(Min)
- · Fast Switching Speed
- · Wide Area of Safe Operation
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

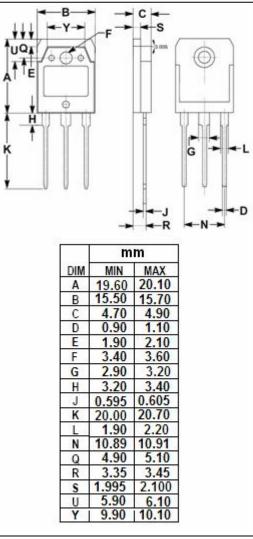
APPLICATIONS

- · Switching regulator and high voltage switching applications
- High speed DC-DC converter applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	900	٧	
$V_{\sf CEO}$	Collector-Emitter Voltage	٧		
V _{EBO}	Emitter-Base Voltage	V		
lc	Collector Current-Continuous	А		
Ісм	Collector Current-Peak 5		Α	
I _B	Base Current-Continuous	0.8	Α	
Pc	Collector Power Dissipation @ T _C =25 °C		W	
TJ	Junction Temperature	150	$^{\circ}$	
T _{stg}	Storage Temperature Range	-55~150	${\mathbb C}$	







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ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 5mA; R _{BE} = ∞	800			V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	I _C = 1mA; I _E = 0	900			V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	I _E = 1mA; I _C = 0	7			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 0.75A; I _B = 0.15A			2.0	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 0.75A; I _B = 0.15A			1.5	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 800V; I _E = 0			10	μ Α
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0			10	μ Α
h _{FE-1}	DC Current Gain	I _C = 0.1A; V _{CE} = 5V	10		40	
h _{FE-2}	DC Current Gain	I _C = 0.5A; V _{CE} = 5V	8			
f⊤	Current-Gain—Bandwidth Product	I _C = 0.1A; V _{CE} = 10V		15		MHz
Сов	Output Capacitance	I _E = 0; V _{CB} = 10V		30		pF
Switching ti	mes		1			
t _r	Rise Time				1.0	μS
t _{stg}	Storage Time	I_C = 1A; I_{B1} = 0.2A; I_{B2} = -0.4A; R_L = 400 Ω ; V_{CC} = 400V			3.0	μS
t _f	Fall Time	, 			0.7	μs

♦ h_{FE-1} Classifications

K	L	M
10-20	15-30	20-40

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